





#### NPN SILICON PLANAR MEDIUM POWER TRANSISTOR IN SOT223

#### **Features**

- BV<sub>CEO</sub> > 40V
- Max Continuous Current I<sub>C</sub> = 1A
- Low saturation voltage V<sub>CE(sat)</sub> < 500mV @ 1A</li>
- Complementary PNP Type: FZT591A
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP capable (Note 4)

# Mechanical Data

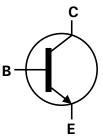
- Case: SOT223
- Case material: molded plastic. "Green" molding compound.
- UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208
- Weight: 0.112 grams (approximate)

#### **Applications**

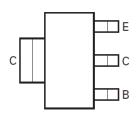
- Power MOSFET gate driving
- Low loss power switching



Top View



Device Symbol



Top View Pin-Out

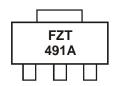
### Ordering Information (Notes 4 & 5)

Product	Compliance	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
FZT491ATA	AEC-Q101	FZT491A	7	12	1,000
FZT491AQTA	Automotive	FZT491A	7	12	1,000

Notes:

- 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
- 2. See http://www.diodes.com for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified.
- 5. For packaging details, go to our website at http://www.diodes.com

## **Marking Information**



FZT491A = Product Type Marking Code





FZT491A

#### **Maximum Ratings** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	40	V
Collector-Emitter Voltage	V <sub>CEO</sub>	40	V
Emitter-Base Voltage	V <sub>EBO</sub>	7	V
Continuous Collector Current	Ic	1	Α
Base Current	I <sub>B</sub>	200	mA
Peak Pulse Current	I <sub>CM</sub>	2	Α

#### **Thermal Characteristics**

Characteristic	Symbol	Value	Unit	
Power Dissipation	(Note 6)	D	2	W
Power Dissipation	(Note 7)	P <sub>D</sub>	3	W
Thermal Desistance Junation to Ambient	(Note 6)	0	62.5	°C/W
Thermal Resistance, Junction to Ambient	(Note 7)	R <sub>0JA</sub>	41.7	°C/W
Thermal Resistance, Junction to Leads (Note	$R_{\theta JL}$	19.41	°C/W	
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C	

## ESD Ratings (Note 9)

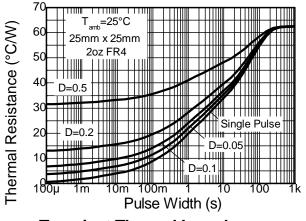
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	≥ 8,000	٧	3B
Electrostatic Discharge - Machine Model	ESD MM	≥ 400	V	С

Notes:

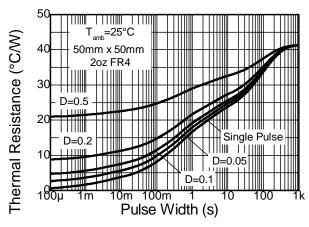
- 6. For a device surface mounted on 25mm X 25mm FR4 PCB with high coverage of single sided 1 oz copper, in still air conditions; device measured when operating in steady state condition.
- 7. Same as note (6), except the device is mounted on 50mm X 50mm single sided 2oz weight copper.
- 8. Thermal resistance from junction to solder-point (at the end of the collector lead).
  9. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



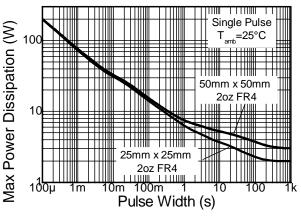
# **Thermal Characteristics and Derating Information**



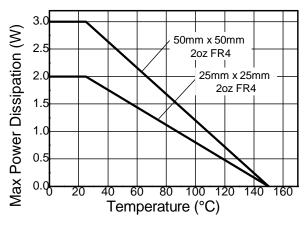
**Transient Thermal Impedance** 



**Transient Thermal Impedance** 



**Pulse Power Dissipation** 



**Derating Curve** 





FZT491A

# **Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

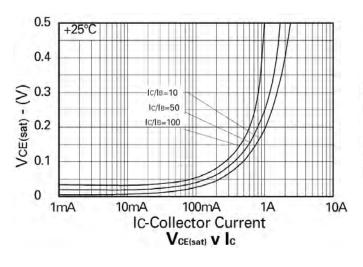
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	40	_	_	V	$I_C = 100\mu A$
Collector-Emitter Breakdown Voltage (Note 10)	BV <sub>CEO</sub>	40	_	_	V	$I_C = 10mA$
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	7	_	_	V	$I_E = 100\mu A$
Collector Cut-off Current	I <sub>CBO</sub>	_	_	100	nA	$V_{CB} = 30V$
Collector Cut-off Current	I <sub>CES</sub>	-	_	100	nA	V <sub>CES</sub> = 30V
Emitter Cut-off Current	I <sub>EBO</sub>	_	_	100	nA	$V_{EB} = 4V$
Collector-Emitter Saturation Voltage (Note 10)	V <sub>CE(sat)</sub>	_ _	- -	0.3 0.5	V	$I_C = 500 \text{mA}, I_B = 50 \text{mA}$ $I_C = 1A, I_B = 100 \text{mA}$
Base-Emitter Saturation Voltage (Note 10)	V <sub>BE(sat)</sub>	_	_	1.1	V	$I_C = 1A$ , $I_B = 100mA$
Base-Emitter Turn-On Voltage (Note 10)	V <sub>BE(on)</sub>	_	_	1.0	V	$I_C = 1A$ , $V_{CE} = 5V$
DC Current Gain (Note 10)	h <sub>FE</sub>	300 300 200 35	= - - -	900 - -		$I_C = 1 \text{mA}, V_{CE} = 5 \text{V}$ $I_C = 500 \text{mA}, V_{CE} = 5 \text{V}$ $I_C = 1 \text{A}, V_{CE} = 5 \text{V}$ $I_C = 2 \text{A}, V_{CE} = 5 \text{V}$
Current Gain-Bandwidth Product (Note 10)	f <sub>T</sub>	150	-	-	MHz	$V_{CE} = 10V, I_{C} = 50mA$ f = 100MHz
Output Capacitance (Note 10)	$C_obo$	-	_	10	pF	V <sub>CB</sub> = 10V. f = 1MHz

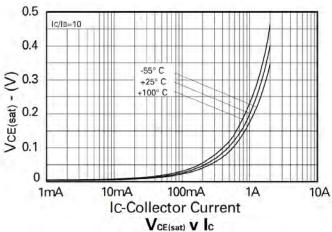
Notes: 10. Measured under pulsed conditions. Pulse width  $\leq$  300 $\mu$ s. Duty cycle  $\leq$  2%

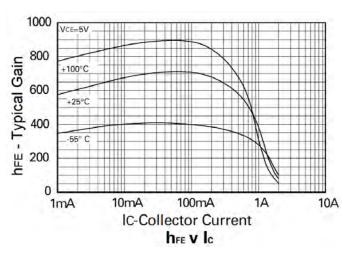


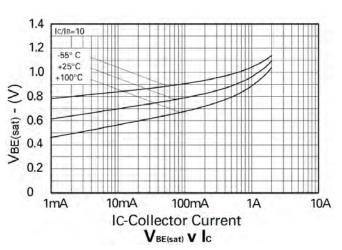
FZT491A

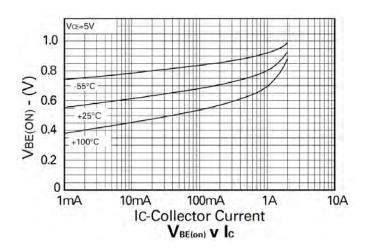
## Typical Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)







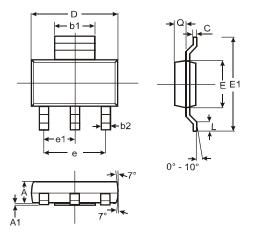






# **Package Outline Dimensions**

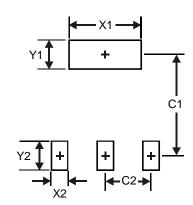
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



SOT223					
Dim	Min	Max	Тур		
Α	1.55	1.65	1.60		
A1	0.010	0.15	0.05		
b1	2.90	3.10	3.00		
b2	0.60	0.80	0.70		
C	0.20	0.30	0.25		
D	6.45	6.55	6.50		
Е	3.45	3.55	3.50		
E1	6.90	7.10	7.00		
е	_	_	4.60		
e1	_	_	2.30		
L	0.85	1.05	0.95		
ø	0.84	0.94	0.89		
All [	All Dimensions in mm				

# **Suggested Pad Layout**

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
X1	3.3
X2	1.2
Y1	1.6
Y2	1.6
C1	6.4
Co	2.2





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